## NLHV4157N

## Negative Voltage SPDT Switch

The NLHV4157N is an advanced CMOS analog switch fabricated with silicon gate CMOS technology. The device passes analog and digital negative voltages that may vary across the full power-supply range (from $\mathrm{V}_{\mathrm{EE}}$ to GND).

## Features

- Operating Voltage Range: $\mathrm{V}_{\mathrm{EE}}=-12 \mathrm{~V}$ to -4 V
- Switch Signal Voltage Range: $\mathrm{V}_{\mathrm{IS}}=\mathrm{V}_{\mathrm{EE}}$ to GND
- Positive Control Signal Voltage: $\mathrm{V}_{\mathrm{IN}}=0$ to 3.3 V
- Low ON Resistance: $\mathrm{R}_{\mathrm{ON}} \leq 5 \Omega$ @ $\mathrm{V}_{\mathrm{EE}}=-10 \mathrm{~V}$
- Latch-up Performance Exceeds 200 mA
- Available in: SC-88 6-Pin Package
- These Devices are $\mathrm{Pb}-$ Free, Halogen-Free/BFR-Free and are RoHS-Compliant


Figure 1. Pin Assignment and logic Diagram

ON Semiconductor ${ }^{\circledR}$
www.onsemi.com
MARKING
DIAGRAM
SF SUFFIX
CASE 419B
(Note: Microdot may be in either location)
*Date Code orientation and/or position may vary depending upon manufacturing location.

FUNCTION TABLE

| Select Input | Function |
| :---: | :---: |
| L | B0 Connected to A |
| H | B1 Connected to A |

ORDERING INFORMATION

| Device | Package | Shipping $^{\dagger}$ |
| :---: | :---: | :---: |
| NLHV4157NDFT2G | SC-88 <br> $($ Pb-Free $)$ |  <br> Reel |

$\dagger$ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

## NLHV4157N

MAXIMUM RATINGS

| Symbol | Rating | Value | Unit |
| :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{EE}}$ | DC Supply Voltage | -13 to +0.5 | V |
| $V_{\text {IS }}$ | Analog Input Voltage (Note 1) | $\mathrm{V}_{\mathrm{EE}}-0.5$ to +0.5 | V |
| $\mathrm{V}_{\text {IN }}$ | Digital Select Input Voltage (Note 1) | -0.5 to +3.6 | V |
| liok | Switch Input/Output diode current | $\pm 50$ | mA |
| $\mathrm{I}_{\text {IK }}$ | Select input diode current | -50 | mA |
| $\mathrm{P}_{\mathrm{D}}$ | Power Dissipation in Still Air | 60 | mW |
| $\mathrm{T}_{\mathrm{L}}$ | Lead Temperature, 1 mm from Case for 10 seconds | 260 | ${ }^{\circ} \mathrm{C}$ |
| TJ | Junction Bias Under Bias | 150 | ${ }^{\circ} \mathrm{C}$ |
| MSL | Moisture Sensitivity | Level 1 |  |
| $\mathrm{F}_{\mathrm{R}}$ | Flammability Rating Oxygen Index: 30\% - 35\% | UL94-V0 (0.125 in) | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{I}_{\mathrm{L}}$ | Latch-up Current (Note1) | $\begin{aligned} & \pm 200 \\ & \hline \pm 300 \end{aligned}$ | mA |
| $\mathrm{T}_{\mathrm{s}}$ | Storage Temperature | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |
| $\theta_{J A}$ | Thermal Resistance | 400 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| ESD | ESD ProtectionHuman Body Model <br> Machine Model | 3000 150 | V |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. The input and output voltage ratings may be exceeded if the input and output diode current ratings are observed.

RECOMMENDED OPERATING CONDITIONS (Note 2)

| Symbol | Parameter | Min | Max | Unit |
| :---: | :--- | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{EE}}$ | DC Supply Voltage | -12 | -4 | V |
| $\mathrm{~V}_{\mathrm{S}}$ | Switch Input / Output Voltage | $(\mathrm{B} 0, \mathrm{~B} 1, \mathrm{~A})$ | $\mathrm{V}_{\mathrm{EE}}$ | GND |
| $\mathrm{V}_{\mathrm{IN}}$ | Digital Select Input Voltage | GND | 3.3 | V |
| $\mathrm{~T}_{\mathrm{A}}$ | Operating Temperature Range | -55 | +125 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}$ | Input Transition Rise or Fall Time (Select Input) | 0 | 100 | $\mathrm{~ns} / \mathrm{V}$ |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.
2. Select input must be held HIGH or LOW, it must not float.

## NLHV4157N

DC ELECTRICAL CHARACTERISTICS (Voltages referenced to GND; Typical characteristics are $\mathrm{T}_{\mathrm{A}}$ at $25^{\circ} \mathrm{C}$.)

| Symbol |  |  | $-55^{\circ}$ to $125^{\circ} \mathrm{C}$ |  |  |  |  |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | Parameter | Condition |  | Min | Typ | Max | Unit |

## SELECT INPUT

| $\mathrm{V}_{\mathrm{IH}}$ | Minimum High-Level Input Voltage |  | -12 | 1.8 |  | 3.3 | V |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | -10 | 1.6 |  | 3.3 |  |
|  |  |  | -8 | 1.4 |  | 3.3 |  |
|  |  |  | -6 | 1.2 |  | 3.3 |  |
|  |  |  | -4 | 1.0 |  | 3.3 |  |
| $\mathrm{V}_{\text {IL }}$ | Maximum Low-Level Input Voltage |  | -12 | 0 |  | 0.8 | V |
|  |  |  | -10 | 0 |  | 0.7 |  |
|  |  |  | -8 | 0 |  | 0.6 |  |
|  |  |  | -6 | 0 |  | 0.5 |  |
|  |  |  | -4 | 0 |  | 0.4 |  |
| IN | Maximum Input Leakage Current | $\mathrm{V}_{\text {IN }}=3.3 \mathrm{~V}$ or GND | -10 |  | $\pm 0.2$ | $\pm 50$ | $\mu \mathrm{A}$ |
|  |  | $\mathrm{V}_{\mathrm{IN}}=3.3 \mathrm{~V}$ or GND, test at $25^{\circ} \mathrm{C}$ only | -10 |  |  | $\pm 0.5$ |  |

## POWER SUPPLY

| IcC | Maximum Quiescent <br> Supply Current | Select $=3.3$ V or GND, <br> $V_{\text {IS }}=V_{\text {EE }}$ or GND | -10 to -4 | 25 | 80 | $\mu \mathrm{~A}$ |
| :---: | :--- | :--- | :--- | :--- | :--- | :--- | :--- |

ANALOG SWITCH

| R ON | Maximum ON <br> Resistance (Note 3) | $\begin{aligned} & V_{I N}=V_{\text {II }} \text { or } V_{\text {IH }} \\ & V_{I S}=V_{E E} \text { to } G N D \\ & l_{0} \leq 10 \mathrm{~mA} \end{aligned}$ | -12 | 2.6 | 4.5 | $\Omega$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | -10 | 3.0 | 5 |  |
|  |  |  | -8 | 3.5 | 5.8 |  |
|  |  |  | -6 | 4.5 | 7.5 |  |
|  |  | $\begin{aligned} & V_{I N}=V_{I L} \text { or } V_{I H} \\ & V_{I S}=V_{E E} \text { to } G N D \\ & l_{0} \leq 5 \mathrm{~mA} \end{aligned}$ | -4 | 9 | 15 |  |
| $\mathrm{R}_{\text {FLAT }}$ | ON Resistance <br> Flatness (Notes 3, 4, 6) | $\begin{aligned} & \mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{II}} \text { or } \mathrm{V}_{\mathrm{IH}} \\ & \mathrm{~V}_{\mathrm{IS}}=\mathrm{V}_{\mathrm{EE}} \text { to } G N D \\ & \mathrm{I}_{\mathrm{O}} \leq 10 \mathrm{~mA} \end{aligned}$ | -12 | 0.4 |  | $\Omega$ |
|  |  |  | -10 | 1.2 |  |  |
|  |  |  | -8 | 1.7 |  |  |
|  |  |  | -6 | 2.5 |  |  |
|  |  | $\begin{aligned} & V_{I N}=V_{I L} \text { or } V_{I H} \\ & V_{I S}=V_{E E} \text { to } G N D \\ & l_{0} \leq 5 \mathrm{~mA} \end{aligned}$ | -4 | 6 |  |  |
| $\Delta \mathrm{R}_{\text {ON }}$ | Ron Mismatch Between (Notes 3, 4, 5) | $\mathrm{I}_{\mathrm{A}}=-10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{Bn}}=-8.4 \mathrm{~V}$ | -12 | 0.2 |  | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{A}}=-10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{Bn}}=-7 \mathrm{~V}$ | -10 | 0.2 |  |  |
|  |  | $\mathrm{I}_{\mathrm{A}}=-10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{Bn}}=-5.6 \mathrm{~V}$ | -8 | 0.25 |  |  |
|  |  | $\mathrm{I}_{\mathrm{A}}=-10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{Bn}}=-4.2 \mathrm{~V}$ | -6 | 0.25 |  |  |
|  |  | $\mathrm{I}_{\mathrm{A}}=-5 \mathrm{~mA}, \mathrm{~V}_{\mathrm{Bn}}=-2.8 \mathrm{~V}$ | -4 | 0.3 |  |  |
| $I_{\mathrm{NC}(\mathrm{OFF}),}$ $\mathrm{I}_{\mathrm{NO}(\mathrm{OFF})}$ | NC or NO OFF Leakage Current (Figure 9) | $\begin{aligned} & \mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{II}} \text { or } \mathrm{V}_{\mathrm{IH}}, \mathrm{~V}_{\mathrm{Bn}}=\mathrm{GND}, \mathrm{~V}_{\mathrm{A}}=\mathrm{V}_{\mathrm{EE}} \\ & \text { to } \mathrm{GND} \end{aligned}$ | -10 | $\pm 1.0$ | $\pm 20$ | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {COM (ON) }}$ | COM ON Leakage Current (Figure 9) | $\begin{aligned} & V_{I N}=V_{I L} \text { or } V_{I H} ; \\ & V_{A}=G N D V \text { or } V_{E E} ; \\ & V_{B 1}=G N D \text { or } V_{E E} \text { with } V_{B 0} \text { floating, or } \\ & V_{B 0}=G N D \text { or } V_{E E} \text { with } V_{B 1} \text { floating } \end{aligned}$ | -10 | $\pm 2.0$ | $\pm 20$ | $\mu \mathrm{A}$ |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
3. Measured by the voltage drop between A and B pins at the indicated current through the switch. On Resistance is determined by the lower of the voltages on the two (A or B Ports).
4. Parameter is characterized but not tested in production.
5. $\Delta \mathrm{R}_{\mathrm{ON}}=\mathrm{R}_{\mathrm{ON}} \max -\mathrm{R}_{\mathrm{ON}} \mathrm{min}$ measured at identical $\mathrm{V}_{\mathrm{EE}}$, temperature and voltage levels.
6. Flatness is defined as the difference between the maximum and minimum value of ON Resistance over the specified range of conditions.

## NLHV4157N

AC ELECTRICAL CHARACTERISTICS (Voltages referenced to GND; Typical characteristics are $\mathrm{T}_{\mathrm{A}}$ at $25^{\circ} \mathrm{C}$.)

| Symbol | Parameter | Condition | $\mathrm{V}_{\mathrm{EE}}, \mathrm{V}$ | $-55^{\circ}$ to $125^{\circ} \mathrm{C}$ |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | Min | Typ | Max |  |
| $\mathrm{t}_{\text {PHL }}$, tPLH | Propagation Delay, Bus to Bus (Note 8) ( A to $\mathrm{B}_{\mathrm{n}}$ ) | $\mathrm{C}_{\mathrm{L}}=100 \mathrm{pF}$ (Figures 2, 3) | -12 to -4 |  |  | 2 | ns |
| $t_{\text {PZL }}, \mathrm{t}_{\text {PZH }}$ | Switch Enable Time Turn-On Time (A to $B_{n}$ ) | $\mathrm{C}_{\mathrm{L}}=100 \mathrm{pF}$ (Figures 2, 3) | -12 |  |  | 220 | ns |
|  |  |  | -10 |  |  | 175 |  |
|  |  |  | -8 |  |  | 165 |  |
|  |  |  | -6 |  |  | 165 |  |
|  |  |  | -4 |  |  | 200 |  |
| $\mathrm{t}_{\text {PLZ }}, \mathrm{t}_{\text {PHZ }}$ | Switch Disable Time Turn-Off Time (A to $\mathrm{B}_{\mathrm{n}}$ ) | $\mathrm{C}_{\mathrm{L}}=100 \mathrm{pF}$ (Figures 2, 3) | -12 |  |  | 225 | ns |
|  |  |  | -10 |  |  | 155 |  |
|  |  |  | -8 |  |  | 150 |  |
|  |  |  | -6 |  |  | 120 |  |
|  |  |  | -4 |  |  | 145 |  |
| $\mathrm{t}_{\mathrm{B}}$ | Switch Break Time | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=100 \mathrm{pF}, \\ & \mathrm{~V}_{1 \mathrm{~S}}=-2.5 \mathrm{~V} \text { (Figure 4) } \end{aligned}$ | -12 | 5 |  | 60 | ns |
|  |  |  | -10 | 5 |  | 60 |  |
|  |  |  | -8 | 10 |  | 75 |  |
|  |  |  | -6 | 10 |  | 90 |  |
|  |  |  | -4 | 40 |  | 135 |  |
| tpor | Power ON Reset Time | Measured from $\mathrm{V}_{\mathrm{EE}}=-4 \mathrm{~V}$ | -12 to -4 |  |  | 20 | us |
| Q | Charge Injection (Note 7) | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=1 \mathrm{nF}, \mathrm{~V}_{\mathrm{GEN}}=0 \mathrm{~V}, \\ & \mathrm{R}_{\mathrm{GEN}}=0 \Omega \text { (Figure 5) } \end{aligned}$ | -12 |  | 170 |  | pC |
|  |  |  | -10 |  | 120 |  |  |
|  |  |  | -8 |  | 95 |  |  |
|  |  |  | -6 |  | 55 |  |  |
|  |  |  | -4 |  | 40 |  |  |
| OIRR | Off-Isolation (Note 9) | $\mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{f}=10 \mathrm{MHz}$ (Figure 6) | -12 to -4 |  | -33 |  | dB |
| Xtalk | Crosstalk | $\mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{f}=10 \mathrm{MHz}$ (Figure 7) | -12 to -4 |  | -42 |  | dB |
| BW | -3 dB Bandwidth | $\mathrm{R}_{\mathrm{L}}=50 \Omega$ (Figure 10) | -12 to -4 |  | 200 |  | MHz |

7. Guaranteed by Design.
8. This parameter is guaranteed by design but not tested. The bus switch contributes no propagation delay other than the RC delay of the ON Resistance of the switch and the 50 pF load capacitance, when driven by an ideal voltage source (zero output impedance).
9. Off Isolation $=20 \log 10[\mathrm{VA} / \mathrm{VBn}]$.

CAPACITANCES (Note 10)

| Symbol | Parameter | Test Conditions | Typical @ 25 ${ }^{\circ} \mathbf{C}$ | Unit |
| :---: | :--- | :---: | :---: | :---: |
| $\mathrm{C}_{\mathrm{IN}}$ | Input Capacitance, Select Inputs | $\mathrm{V}_{\mathrm{EE}}=-12 \mathrm{~V}$ | 6 | pF |
| $\mathrm{C}_{\mathrm{IOB}}$ | B-Port OFF Capacitance | $\mathrm{V}_{\mathrm{EE}}=-10 \mathrm{~V}$ | 45 | pF |
| $\mathrm{C}_{\mathrm{IOA}} \mathrm{ON}$ | A Port Capacitance when Switch is Enabled | $\mathrm{V}_{\mathrm{EE}}=-10 \mathrm{~V}$ | 100 | pF |

$10 . T_{A}=+25^{\circ} \mathrm{C}, f=1 \mathrm{MHz}$, Capacitance is characterized but not tested in production.


Note: Input $\mathrm{V}_{\text {IS }}$ driven by $50 \Omega$ source terminated by $50 \Omega$.
Note: $\mathrm{C}_{\mathrm{L}}$ includes load and stray capacitance. Input PRR $=100 \mathrm{kHz}, \mathrm{t}_{\mathrm{w}}=5 \boldsymbol{\mu} \mathrm{~s}$.

| Parameter | $\mathbf{V}_{\mathbf{I}}$ | $\mathbf{V}_{\mathbf{I S}}$ |
| :---: | :---: | :---: |
| $\mathrm{t}_{\text {PLH }} / \mathrm{t}_{\text {PHL }}$ | Open | Source |
| $\mathrm{t}_{\text {PZL }} / \mathrm{t}_{\text {PLZ }}$ | GND | $\mathrm{V}_{\mathrm{EE}}$ |
| $\mathrm{t}_{\mathrm{PZH}} / \mathrm{t}_{\text {PHZ }}$ | $2 \times \mathrm{V}_{\mathrm{EE}}$ | GND |

Figure 2. AC Test Circuit


Figure 3. AC Test Waveforms

## NLHV4157N



Figure 4. Switch Break Interval Timing


Figure 5. Charge Injection Test


Figure 6. Off Isolation

Figure 8. Channel Off Capacitance



Figure 7. Crosstalk


Figure 9. Channel On Capacitance

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Figure 10. Bandwidth


Figure 11. Typical Application

## NLHV4157N

## PACKAGE DIMENSIONS



